



BC857AT, BT, CT

PNP SMALL SIGNAL SURFACE MOUNT TRANSISTOR

Features

Epitaxial Die Construction Complementary NPN Types Available (BC847AT, BT, CT)

Ultra-Small Surface Mount Package Lead Free/RoHS Compliant (Note 2)

Qualified to AEC-Q101 Standards for High Reliability

Mechanical Data

Case: SOT-523

Case Material: Molded Plastic. UL Flammability

Classification Rating 94V-0

Moisture Sensitivity: Level 1 per J-STD-020C

Terminals: Solderable per MIL-STD-202, Method 208

Lead Free Plating (Matte Tin Finish annealed over Alloy 42

leadframe).

Terminal Connections: See Diagram

Marking Codes (See Table Below & Diagrams on Page 2)

Ordering & Date Code Information: See Page 2

Weight: 0.002 grams (approximate)

| _ | A A C | |
|---|--|---|
| | THE HOLD MAN AND AND AND AND AND AND AND AND AND A |) |

| | SOT-523 | | | | | | | | | |
|----------------------|---------|------|------|--|--|--|--|--|--|--|
| Dim | Min | Max | Тур | | | | | | | |
| Α | 0.15 | 0.30 | 0.22 | | | | | | | |
| В | 0.75 | 0.85 | 0.80 | | | | | | | |
| С | 1.45 | 1.75 | 1.60 | | | | | | | |
| D | | | 0.50 | | | | | | | |
| G | 0.90 | 1.10 | 1.00 | | | | | | | |
| Н | 1.50 | 1.70 | 1.60 | | | | | | | |
| J | 0.00 | 0.10 | 0.05 | | | | | | | |
| K | 0.60 | 0.80 | 0.75 | | | | | | | |
| L | 0.10 | 0.30 | 0.22 | | | | | | | |
| М | 0.10 | 0.20 | 0.12 | | | | | | | |
| N | 0.45 | 0.65 | 0.50 | | | | | | | |
| | 0 | 8 | | | | | | | | |
| All Dimensions in mm | | | | | | | | | | |

| Туре | Marking |
|---------|---------|
| BC857AT | 3V |
| BC857BT | 3W |
| BC857CT | 3G |

Maximum Ratings @ T_A = 25°C unless otherwise specified

| Characteristic | Symbol | Value | Unit |
|--|-----------------------------------|-------------|------|
| Collector-Base Voltage | V _{CBO} | -50 | V |
| Collector-Emitter Voltage | V _{CEO} | -45 | V |
| Emitter-Base Voltage | V _{EBO} | -5.0 | V |
| Collector Current | Ic | -100 | mA |
| Power Dissipation (Note 1) | P _d | 150 | mW |
| Thermal Resistance, Junction to Ambient (Note 1) | R _{JA} | 833 | °C/W |
| Operating and Storage Temperature Range | T _j , T _{STG} | -55 to +150 | °C |

Notes

- 1. Device mounted on FR-4 PCB, 1 inch x 0.85 inch x 0.062 inch; pad layout as shown on Diodes Inc. suggested pad layout document AP02001, which can be found on our website at http://www.diodes.com/datasheets/ap02001.pdf.
- 2. No purposefully added lead.



Electrical Characteristics @ $T_A = 25$ °C unless otherwise specified

| Characteristic | Symbol | Min | Тур | Max | Unit | Test Condition |
|---|----------------------|-------------------|-----------------|-------------------|----------|---|
| Collector-Base Breakdown Voltage (Note 3) | V _{(BR)CBO} | -50 | _ | _ | V | I _C = 10 A, I _B = 0 |
| Collector-Emitter Breakdown Voltage (Note 3) | V _{(BR)CEO} | -45 | _ | _ | V | $I_C = 10 \text{mA}, I_B = 0$ |
| Emitter-Base Breakdown Voltage (Note 3) | V _{(BR)EBO} | -5 | _ | _ | V | I _E = 1 A, I _C = 0 |
| DC Current Gain (Note 3) Current Gain A B C | h _{FE} | 125 220 420 | — 290 520 | 250 475 800 | _ | V _{CE} = -5.0V, I _C = -2.0mA |
| Collector-Emitter Saturation Voltage (Note 3) | V _{CE(SAT)} | _ | _ | -300 -650 | mV | $I_C = -10$ mA, $I_B = -0.5$ mA $I_C = -100$ mA, $I_B = -5.0$ mA |
| Base-Emitter Saturation Voltage (Note 3) | V _{BE(SAT)} | | -700 -900 | _ | mV | $I_C = -10$ mA, $I_B = -0.5$ mA $I_C = -100$ mA, $I_B = -5.0$ mA |
| Base-Emitter Voltage (Note 3) | V _{BE(ON)} | -600 — | _ | -750 -820 | mV | $V_{CE} = -5.0V$, $I_{C} = -2.0$ mA $V_{CE} = -5.0V$, $I_{C} = -10$ mA |
| Collector-Cutoff Current (Note 3) | I _{CBO} | _ | | -15 -4.0 | NA μA | V _{CB} = -30V V _{CB} = -30V, T _A = 150°C |
| Gain Bandwidth Product | f _T | 100 | _ | _ | MHz | $V_{CE} = -5.0V, I_{C} = -10mA,$ f = 100MHz |
| Output Capacitance | Сов | _ | _ | 4.5 | pF | V _{CB} = -10V, f = 1.0MHz |
| Noise Figure | NF | _ | _ | 10 | dB | $I_C = -0.2$ mA, $V_{CE} = -5.0$ Vdc, $R_S = 2.0$ K , $f = 1.0$ KHz, BW = 200Hz |

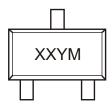
Notes: 3. Short duration pulse test used to minimize self-heating effect.

Ordering Information (Note 4)

| Device | Packaging | Shipping |
|-------------|-----------|------------------|
| BC857AT-7-F | SOT-523 | 3000/Tape & Reel |
| BC857BT-7-F | SOT-523 | 3000/Tape & Reel |
| BC857CT-7-F | SOT-523 | 3000/Tape & Reel |

4. For Packaging Details: go to our website at http://www.diodes.com/datasheets/ap02007.pdf. Notes:

Marking Information



XX = Product Type Marking Code (See Page 1), e.g. 3V = BC857AT

YM = Date Code Marking Y = Year (ex: N = 2002) M = Month (ex: 9 = September)

Date Code Key

| Year | 1998 | 1999 | 2000 | 2001 | 2002 | 2003 | 2004 | 2005 | 2006 | 2007 | 2008 | 2009 | 2010 | 2011 | 2012 |
|------|------|------|------|------|------|------|------|------|------|------|------|------|------|------|------|
| Code | J | K | L | М | N | Р | R | S | Т | U | V | W | Х | Υ | Z |

| Month | Jan | Feb | March | Apr | May | Jun | Jul | Aug | Sep | Oct | Nov | Dec | |
|-------|-----|-----|-------|-----|-----|-----|-----|-----|-----|-----|-----|-----|--|
| Code | 1 | 2 | 3 | 4 | 5 | 6 | 7 | 8 | 9 | 0 | N | D | |



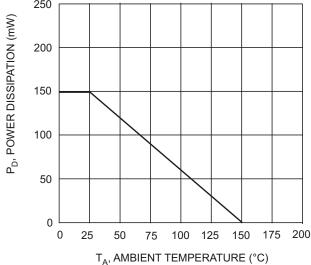
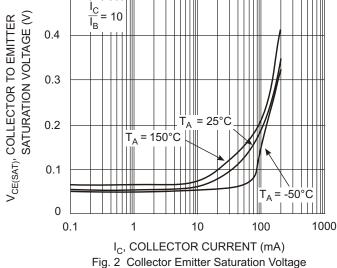
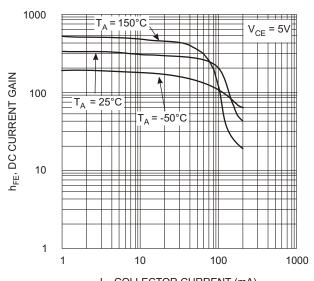


Fig. 1, Max Power Dissipation vs Ambient Temperature

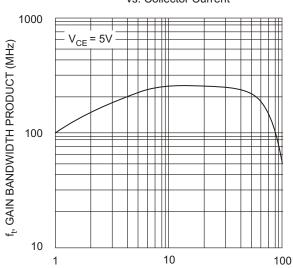


0.5

vs. Collector Current



I_C, COLLECTOR CURRENT (mA) Fig. 3, DC Current Gain vs. Collector Current



I_C, COLLECTOR CURRENT (mA) Fig. 4, Gain Bandwidth Product vs Collector Current

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